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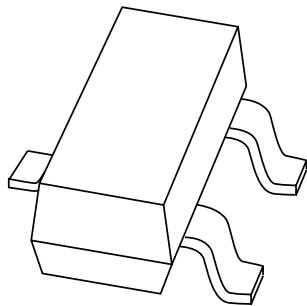
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Kind regards,

Team Nexperia

DATA SHEET



PMBT4401 NPN switching transistor

Product data sheet
Supersedes data of 1999 Apr 15

2004 Jan 21

NPN switching transistor

PMBT4401

FEATURES

- High current (max. 600 mA)
- Low voltage (max. 40 V).

APPLICATIONS

- Industrial and consumer switching applications.

DESCRIPTION

NPN switching transistor in a SOT23 plastic package.
PNP complement: PMBT4403.

MARKING

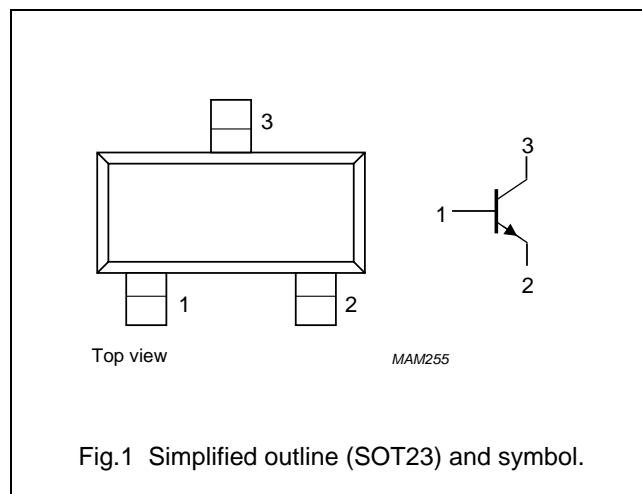
TYPE NUMBER	MARKING CODE ⁽¹⁾
PMBT4401	*2X

Note

1. * = p : Made in Hong Kong.
 * = t : Made in Malaysia.
 * = W : Made in China.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
PMBT4401	–	plastic surface mounted package; 3 leads	SOT23

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter	–	60	V
V_{CEO}	collector-emitter voltage	open base	–	40	V
V_{EBO}	emitter-base voltage	open collector	–	6	V
I_C	collector current (DC)		–	600	mA
I_{CM}	peak collector current		–	800	mA
I_{BM}	peak base current		–	200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$; note 1	–	250	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

NPN switching transistor

PMBT4401

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th(j-a)}$	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector-base cut-off current	$I_E = 0$; $V_{CB} = 60\text{ V}$	—	50	nA
I_{EBO}	emitter-base cut-off current	$I_C = 0$; $V_{EB} = 6\text{ V}$	—	50	nA
h_{FE}	DC current gain	$V_{CE} = 1\text{ V}$; (see Fig.2)			
		$I_C = 0.1\text{ mA}$	20	—	
		$I_C = 1\text{ mA}$	40	—	
		$I_C = 10\text{ mA}$	80	—	
		$I_C = 150\text{ mA}$; note 1	100	300	
		$I_C = 500\text{ mA}$; $V_{CE} = 2\text{ V}$; note 1	40	—	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 150\text{ mA}$; $I_B = 15\text{ mA}$; note 1	—	400	mV
		$I_C = 500\text{ mA}$; $I_B = 50\text{ mA}$; note 1	—	750	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = 150\text{ mA}$; $I_B = 15\text{ mA}$; note 1	—	950	mV
		$I_C = 500\text{ mA}$; $I_B = 50\text{ mA}$; note 1	—	1.2	V
C_c	collector capacitance	$I_E = I_e = 0$; $V_{CB} = 5\text{ V}$; $f = 1\text{ MHz}$	—	8	pF
C_e	emitter capacitance	$I_C = I_c = 0$; $V_{EB} = 500\text{ mV}$; $f = 1\text{ MHz}$	—	30	pF
f_T	transition frequency	$I_C = 20\text{ mA}$; $V_{CE} = 10\text{ V}$; $f = 100\text{ MHz}$	250	—	MHz
Switching times (between 10% and 90% levels); (see Fig.3)					
t_{on}	turn-on time	$I_{Con} = 150\text{ mA}$; $I_{Bon} = 15\text{ mA}$; $I_{Boff} = -15\text{ mA}$	—	35	ns
t_d	delay time		—	15	ns
t_r	rise time		—	20	ns
t_{off}	turn-off time		—	250	ns
t_s	storage time		—	200	ns
t_f	fall time		—	60	ns

Note

1. Pulse test: $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$.

NPN switching transistor

PMBT4401

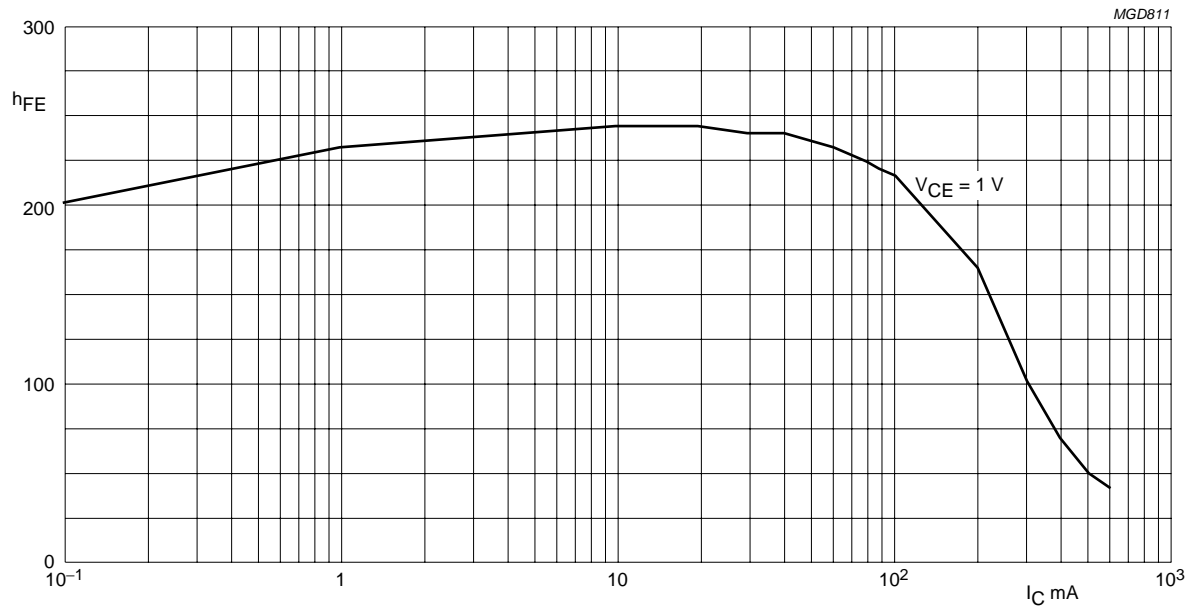
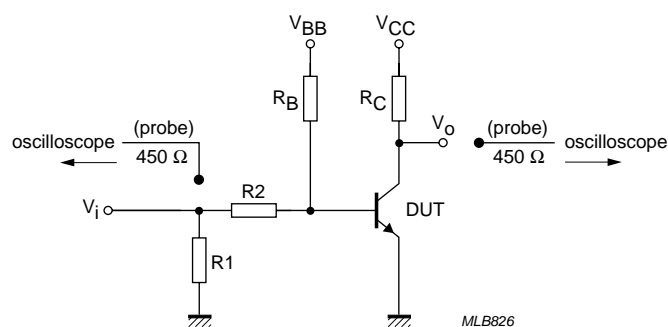


Fig.2 DC current gain; typical values.



V_i = 9.5 V; T = 500 μs; t_p = 10 μs; t_r = t_f ≤ 3 ns.
 R₁ = 68 Ω; R₂ = 325 Ω; R_B = 325 Ω; R_C = 160 Ω.
 V_{BB} = -3.5 V; V_{CC} = 29.5 V.
 Oscilloscope: input impedance Z_i = 50 Ω.

Fig.3 Test circuit for switching times.

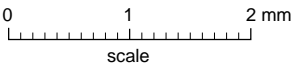
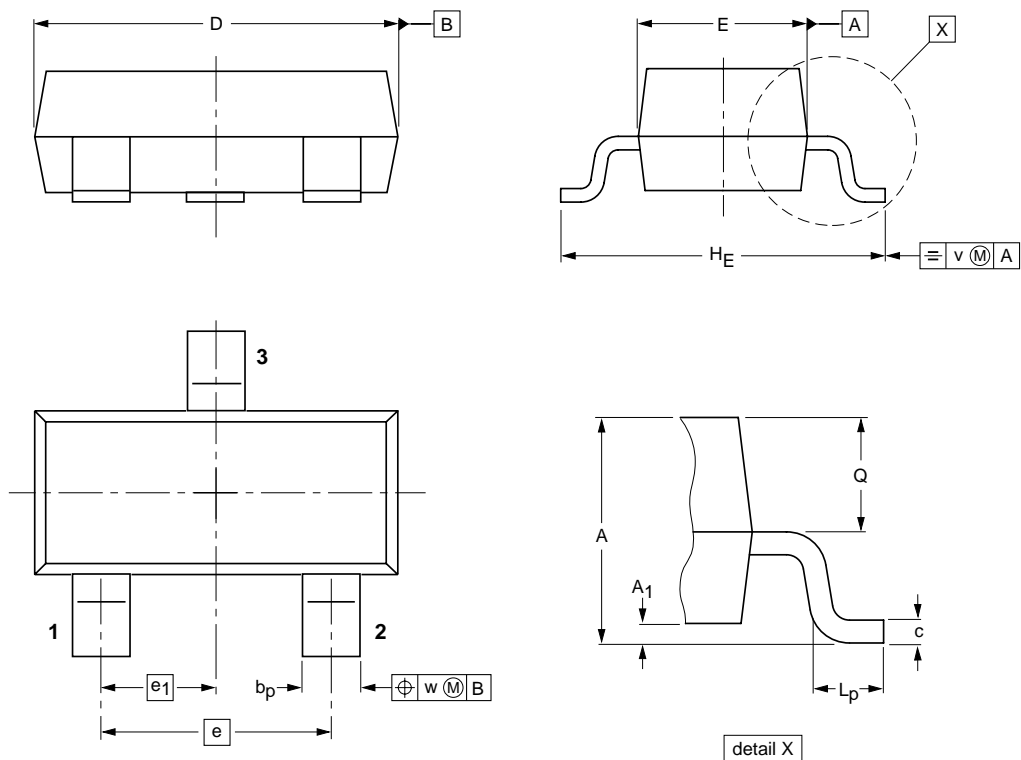
NPN switching transistor

PMBT4401

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT23		TO-236AB				04-11-04 06-03-16

NPN switching transistor

PMBT4401

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: **<http://www.nxp.com>**

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Printed in The Netherlands

R75/04/pp7

Date of release: 2004 Jan 21

Document order number: 9397 750 12462

founded by

PHILIPS



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